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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Not For New Designs
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	32MHz
Connectivity	I ² C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	Brown-out Detect/Reset, Cap Sense, DMA, I ² S, POR, PWM, WDT
Number of I/O	51
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	10K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 20x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l151r8t6

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1 Introduction

This datasheet provides the ordering information and mechanical device characteristics of the STM32L151x6/8/B and STM32L152x6/8/B ultra-low-power ARM® Cortex®-M3 based microcontrollers product line.

The ultra-low-power STM32L151x6/8/B and STM32L152x6/8/B family includes devices in 3 different package types: from 48 to 100 pins. Depending on the device chosen, different sets of peripherals are included, the description below gives an overview of the complete range of peripherals proposed in this family.

These features make the ultra-low-power STM32L151x6/8/B and STM32L152x6/8/B microcontroller family suitable for a wide range of applications:

- Medical and handheld equipment
- Application control and user interface
- PC peripherals, gaming, GPS and sport equipment
- Alarm systems, Wired and wireless sensors, Video intercom
- Utility metering

This STM32L151x6/8/B and STM32L152x6/8/B datasheet should be read in conjunction with the STM32L1xxxx reference manual (RM0038).

The document "Getting started with STM32L1xxxx hardware development" AN3216 gives a hardware implementation overview. Both documents are available from the STMicroelectronics website www.st.com.

For information on the ARM® Cortex®-M3 core please refer to the Cortex®-M3 Technical Reference Manual, available from the www.arm.com website.

Figure 1 shows the general block diagram of the device family.

Caution: This datasheet does not apply to STM32L15xx6/8/B-A covered by a separate datasheet.

3.1 Low power modes

The ultra-low-power STM32L151x6/8/B and STM32L152x6/8/B devices support dynamic voltage scaling to optimize its power consumption in run mode. The voltage from the internal low-drop regulator that supplies the logic can be adjusted according to the system's maximum operating frequency and the external voltage supply:

- In Range 1 (V_{DD} range limited to 1.71-3.6 V), the CPU runs at up to 32 MHz (refer to [Table 17](#) for consumption).
- In Range 2 (full V_{DD} range), the CPU runs at up to 16 MHz (refer to [Table 17](#) for consumption)
- In Range 3 (full V_{DD} range), the CPU runs at up to 4 MHz (generated only with the multispeed internal RC oscillator clock source). Refer to [Table 17](#) for consumption.

Seven low power modes are provided to achieve the best compromise between low power consumption, short startup time and available wakeup sources:

- **Sleep mode**
In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs.
Sleep mode power consumption: refer to [Table 19](#).
- **Low power run mode**
This mode is achieved with the multispeed internal (MSI) RC oscillator set to the minimum clock (65 kHz), execution from SRAM or Flash memory, and internal regulator in low power mode to minimize the regulator's operating current. In the Low power run mode, the clock frequency and the number of enabled peripherals are both limited.
Low power run mode consumption: refer to [Table 20: Current consumption in Low power run mode](#).
- **Low power sleep mode**
This mode is achieved by entering the Sleep mode with the internal voltage regulator in Low power mode to minimize the regulator's operating current. In the Low power sleep mode, both the clock frequency and the number of enabled peripherals are limited; a typical example would be to have a timer running at 32 kHz.
When wakeup is triggered by an event or an interrupt, the system reverts to the run mode with the regulator on.
Low power sleep mode consumption: refer to [Table 21: Current consumption in Low power sleep mode](#).
- **Stop mode with RTC**
Stop mode achieves the lowest power consumption while retaining the RAM and register contents and real time clock. All clocks in the V_{CORE} domain are stopped, the PLL, MSI RC, HSI RC and HSE crystal oscillators are disabled. The LSE or LSI is still running. The voltage regulator is in the low power mode.
The device can be woken up from Stop mode by any of the EXTI line, in 8 μ s. The EXTI line source can be one of the 16 external lines. It can be the PVD output, the Comparator 1 event or Comparator 2 event (if internal reference voltage is on), it can be the RTC alarm(s), the USB wakeup, the RTC tamper events, the RTC timestamp event or the RTC wakeup.
- **Stop mode without RTC**
Stop mode achieves the lowest power consumption while retaining the RAM and register contents. All clocks are stopped, the PLL, MSI RC, HSI and LSI RC, LSE and

3.15.5 Window watchdog (WWDG)

The window watchdog is based on a 7-bit down-counter that can be set as free-running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the main clock. It has an early warning interrupt capability and the counter can be frozen in debug mode.

3.16 Communication interfaces

3.16.1 I²C bus

Up to two I²C bus interfaces can operate in multimaster and slave modes. They can support standard and fast modes.

They support dual slave addressing (7-bit only) and both 7- and 10-bit addressing in master mode. A hardware CRC generation/verification is embedded.

They can be served by DMA and they support SM Bus 2.0/PM Bus.

3.16.2 Universal synchronous/asynchronous receiver transmitter (USART)

All USART interfaces are able to communicate at speeds of up to 4 Mbit/s. They provide hardware management of the CTS and RTS signals and are ISO 7816 compliant. They support IrDA SIR ENDEC and have LIN Master/Slave capability.

All USART interfaces can be served by the DMA controller.

3.16.3 Serial peripheral interface (SPI)

Up to two SPIs are able to communicate at up to 16 Mbits/s in slave and master modes in full-duplex and half-duplex communication modes. The 3-bit prescaler gives 8 master mode frequencies and the frame is configurable to 8 bits or 16 bits. The hardware CRC generation/verification supports basic SD Card/MMC modes.

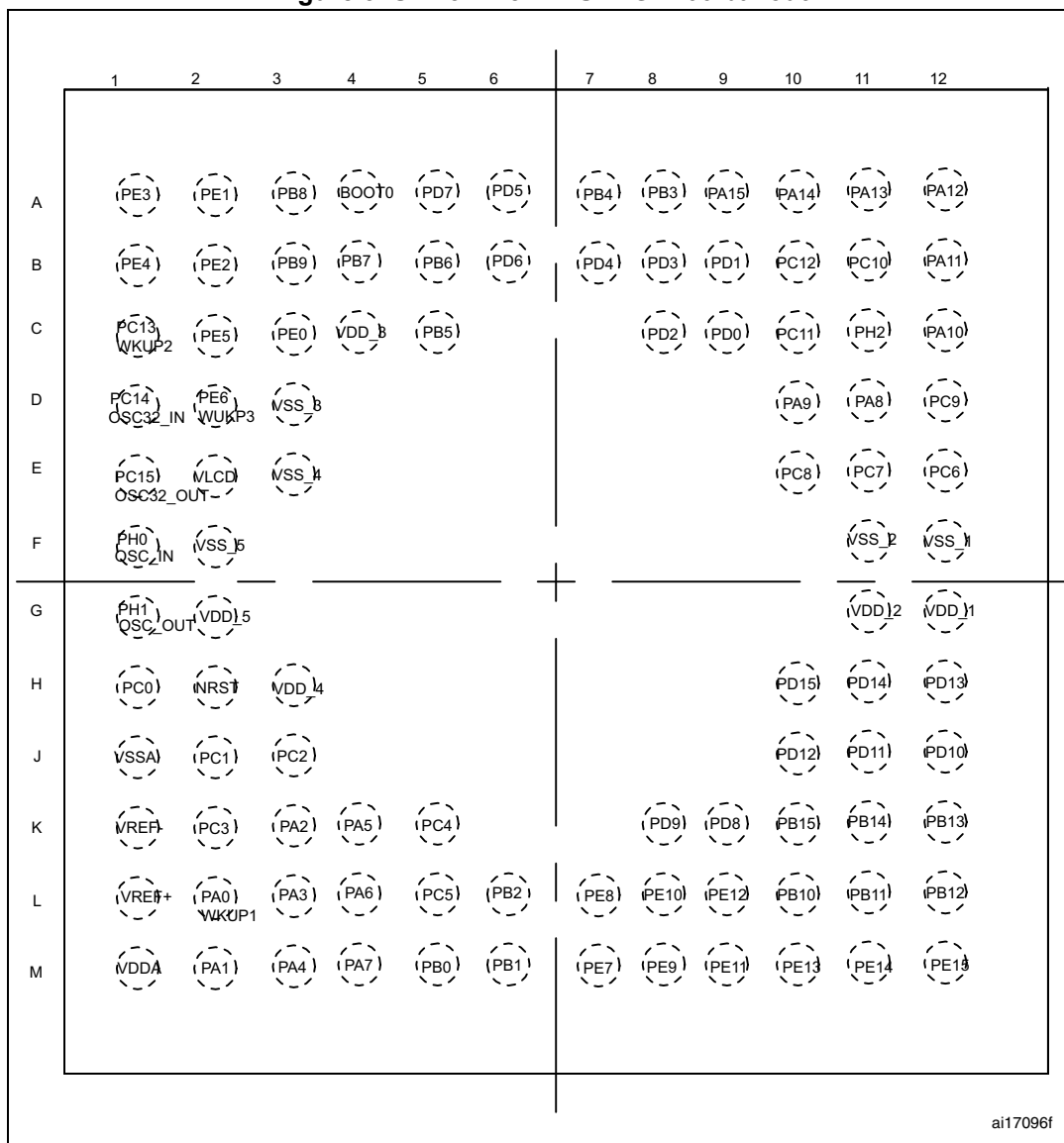
Both SPIs can be served by the DMA controller.

3.16.4 Universal serial bus (USB)

The STM32L151x6/8/B and STM32L152x6/8/B devices embed a USB device peripheral compatible with the USB full speed 12 Mbit/s. The USB interface implements a full speed (12 Mbit/s) function interface. It has software-configurable endpoint setting and supports suspend/resume. The dedicated 48 MHz clock is generated from the internal main PLL (the clock source must use a HSE crystal oscillator).

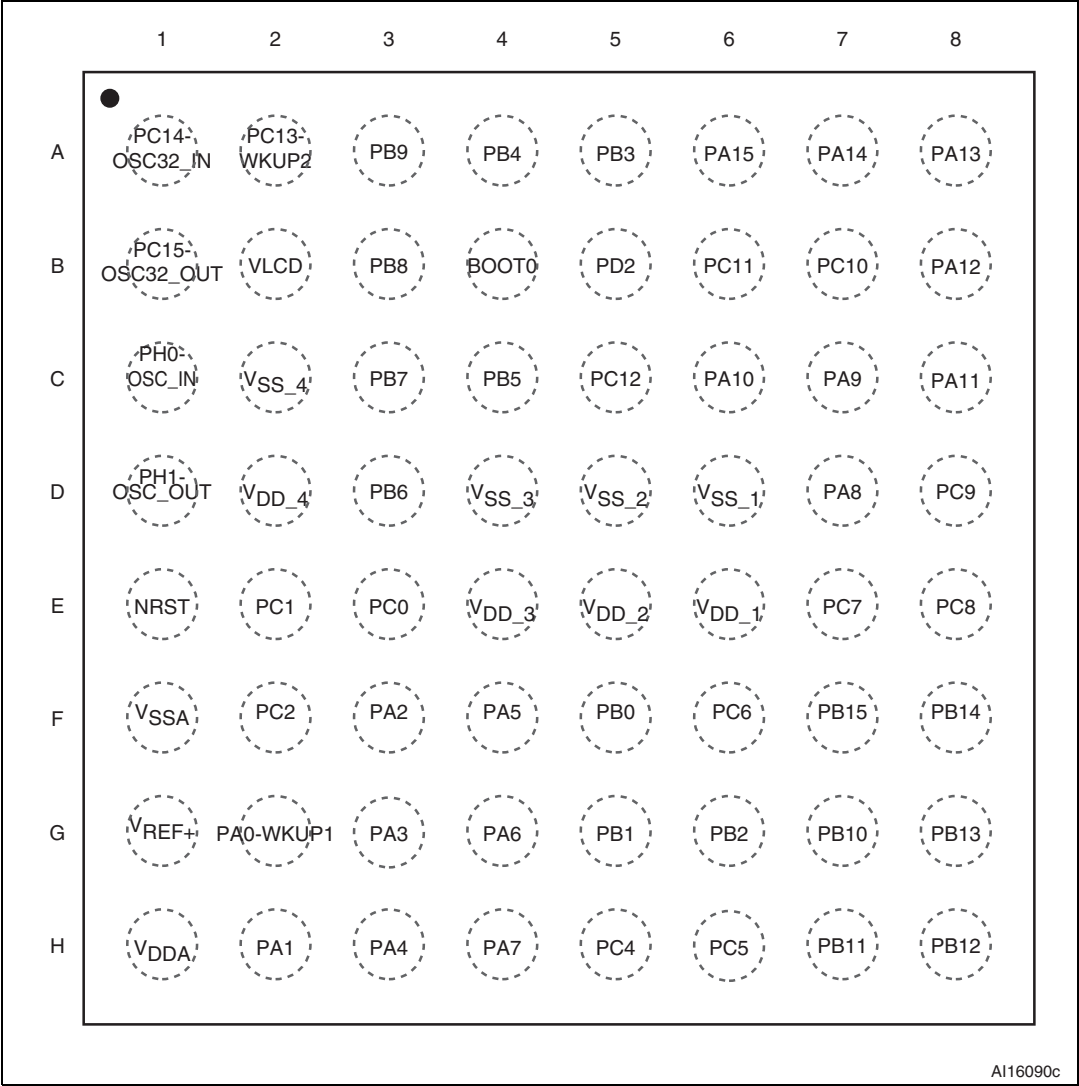
4 Pin descriptions

Figure 3. STM32L15xVx UFBGA100 ballout



1. This figure shows the package top view.

Figure 5. STM32L15xRx TFBGA64 ballout



1. This figure shows the package top view.

Table 8. STM32L151x6/8/B and STM32L152x6/8/B pin definitions

Pins					Pin name	Pin type ⁽¹⁾	I/O structure	Main function ⁽²⁾ (after reset)	Pins functions	Additional functions
LQFP100	LQFP64	TFBGA64	UFBGA100	LQFP48 or UFQFPN48					Alternate functions	
1	-	-	B2	-	PE2	I/O	FT	PE2	TRACECLK/LCD_SEG38/ TIM3_ETR	-
2	-	-	A1	-	PE3	I/O	FT	PE3	TRACED0/LCD_SEG39/ TIM3_CH1	-
3	-	-	B1	-	PE4	I/O	FT	PE4	TRACED1/TIM3_CH2	-
4	-	-	C2	-	PE5	I/O	FT	PE5	TRACED2/TIM9_CH1	-
5	-	-	D2	-	PE6-WKUP3	I/O	FT	PE6	TRACED3/TIM9_CH2	WKUP3
6	1	B2	E2	1	V _{LCD} ⁽³⁾	S		V _{LCD}	-	-
7	2	A2	C1	2	PC13- WKUP2	I/O	FT	PC13	-	RTC_TAMP1/ RTC_TS/ RTC_OUT/ WKUP2
8	3	A1	D1	3	PC14- OSC32_IN ⁽⁴⁾	I/O	TC	PC14	-	OSC32_IN
9	4	B1	E1	4	PC15- OSC32_OUT ⁽⁴⁾	I/O	TC	PC15	-	OSC32_OUT
10	-	-	F2	-	V _{SS_5}	S	-	V _{SS_5}	-	-
11	-	-	G2	-	V _{DD_5}	S	-	V _{DD_5}	-	-
12	5	C1	F1	5	PH0- OSC_IN ⁽⁵⁾	I/O	TC	PH0	-	OSC_IN
13	6	D1	G1	6	PH1- OSC_OUT	I/O	TC	PH1	-	OSC_OUT
14	7	E1	H2	7	NRST	I/O	RST	NRST	-	-
15	8	E3	H1	-	PC0	I/O	FT	PC0	LCD_SEG18	ADC_IN10/ COMP1_INP
16	9	E2	J2	-	PC1	I/O	FT	PC1	LCD_SEG19	ADC_IN11/ COMP1_INP
17	10	F2	J3	-	PC2	I/O	FT	PC2	LCD_SEG20	ADC_IN12/ COMP1_INP
18	11	-(⁶)	K2	-	PC3	I/O	TC	PC3	LCD_SEG21	ADC_IN13/ COMP1_INP

Table 9. Alternate function input/output

Port name	Digital alternate function number														
	AFIO0	AFIO1	AFIO2	AFIO3	AFIO4	AFIO5	AFIO6	AFIO7	AFIO8	AFIO9	AFIO11	AFIO12	AFIO13	AFIO14	AFIO15
	Alternate function														
	SYSTEM	TIM2	TIM3/4	TIM9/10/11	I2C1/2	SPI1/2	N/A	USART1/2/3	N/A	N/A	LCD	N/A	N/A	RI	SYSTEM
BOOT0	BOOT0	-	-	-	-	-	-	-	-	-	-	-	-	-	-
NRST	NRST	-	-	-	-	-	-	-	-	-	-	-	-	-	-
PA0-WKUP1	-	TIM2_CH1_ETR	-	-	-	-	-	USART2_CTS	-	-	-	-	-	TIMx_IC1	EVENTOUT
PA1	-	TIM2_CH2	-	-	-	-	-	USART2_RTS	-	-	[SEG0]	-	-	TIMx_IC2	EVENTOUT
PA2	-	TIM2_CH3	-	TIM9_CH1	-	-	-	USART2_TX	-	-	[SEG1]	-	-	TIMx_IC3	EVENTOUT
PA3	-	TIM2_CH4	-	TIM9_CH2	-	-	-	USART2_RX	-	-	[SEG2]	-	-	TIMx_IC4	EVENTOUT
PA4	-	-	-	-	-	SPI1_NSS	-	USART2_CK	-	-	-	-	-	TIMx_IC1	EVENTOUT
PA5	-	TIM2_CH1_ETR	-	-	-	SPI1_SCK	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PA6	-	-	TIM3_CH1	TIM10_CH1	-	SPI1_MISO	-	-	-	-	[SEG3]	-	-	TIMx_IC3	EVENTOUT
PA7	-	-	TIM3_CH2	TIM11_CH1	-	SPI1_MOSI	-	-	-	-	[SEG4]	-	-	TIMx_IC4	EVENTOUT
PA8	MCO	-	-	-	-	-	-	USART1_CK	-	-	[COM0]	-	-	TIMx_IC1	EVENTOUT
PA9	-	-	-	-	-	-	-	USART1_TX	-	-	[COM1]	-	-	TIMx_IC2	EVENTOUT
PA10	-	-	-	-	-	-	-	USART1_RX	-	-	[COM2]	-	-	TIMx_IC3	EVENTOUT
PA11	-	-	-	-	-	SPI1_MISO	-	USART1_CTS	-	-	-	-	-	TIMx_IC4	EVENTOUT
PA12	-	-	-	-	-	SPI1_MOSI	-	USART1_RTS	-	-	-	-	-	TIMx_IC1	EVENTOUT
PA13	JTMS-SWDIO	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PA14	JTCK-SWCLK	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PA15	JTDI	TIM2_CH1_ETR	-	-	-	SPI1_NSS	-	-	-	-	SEG17	-	-	TIMx_IC4	EVENTOUT
PB0	-	-	TIM3_CH3	-	-	-	-	-	-	-	[SEG5]	-	-	-	EVENTOUT
PB1	-	-	TIM3_CH4	-	-	-	-	-	-	-	[SEG6]	-	-	-	EVENTOUT
PB2	BOOT1	-	-	-	-	-	-	-	-	-	-	-	-	-	EVENTOUT
PB3	JTDO	TIM2_CH2	-	-	-	SPI1_SCK	-	-	-	-	[SEG7]	-	-	-	EVENTOUT
PB4	NJTRST	-	TIM3_CH1	-	-	SPI1_MISO	-	-	-	-	[SEG8]	-	-	-	EVENTOUT



Table 9. Alternate function input/output (continued)

Port name	Digital alternate function number														
	AFIO0	AFIO1	AFIO2	AFIO3	AFIO4	AFIO5	AFIO6	AFIO7	AFIO8	AFIO9	AFIO11	AFIO12	AFIO13	AFIO14	AFIO15
	Alternate function														
	SYSTEM	TIM2	TIM3/4	TIM9/10/11	I2C1/2	SPI1/2	N/A	USART1/2/3	N/A	N/A	LCD	N/A	N/A	RI	SYSTEM
PD13	-	-	TIM4_CH2	-	-	-	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PD14	-	-	TIM4_CH3	-	-	-	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PD15	-	-	TIM4_CH4	-	-	-	-	-	-	-	-	-	-	TIMx_IC4	EVENTOUT
PE0	-	-	TIM4_ETR	TIM10_CH1	-	-	-	-	-	-	-	-	-	TIMx_IC1	EVENTOUT
PE1	-	-		TIM11_CH1	-	-	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PE2	TRACECK	-	TIM3_ETR	-	-	-	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PE3	TRACED0	-	TIM3_CH1	-	-	-	-	-	-	-	-	-	-	TIMx_IC4	EVENTOUT
PE4	TRACED1	-	TIM3_CH2	-	-	-	-	-	-	-	-	-	-	TIMx_IC1	EVENTOUT
PE5	TRACED2	-	-	TIM9_CH1*	-	-	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PE6	TRACED3	-	-	TIM9_CH2*	-	-	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PE7	-	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC4	EVENTOUT
PE8	-	-	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC1	EVENTOUT
PE9	-	TIM2_CH1_ETR	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PE10	-	TIM2_CH2	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PE11	-	TIM2_CH3	-	-	-	-	-	-	-	-	-	-	-	TIMx_IC4	EVENTOUT
PE12	-	TIM2_CH4	-	-	-	SPI1_NSS	-	-	-	-	-	-	-	TIMx_IC1	EVENTOUT
PE13	-	-	-	-	-	SPI1_SCK	-	-	-	-	-	-	-	TIMx_IC2	EVENTOUT
PE14	-	-	-	-	-	SPI1_MISO	-	-	-	-	-	-	-	TIMx_IC3	EVENTOUT
PE15	-	-	-	-	-	SPI1_MOSI	-	-	-	-	-	-	-	TIMx_IC4	EVENTOUT
PH0-OSC_IN	-	-	-	-	-	-	-	-	-	-	-	-	-	-	-

Table 12. Thermal characteristics

Symbol	Ratings	Value	Unit
T_{STG}	Storage temperature range	-65 to +150	°C
T_J	Maximum junction temperature	150	°C

6.3 Operating conditions

6.3.1 General operating conditions

Table 13. General operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
f_{HCLK}	Internal AHB clock frequency	-	0	32	MHz
f_{PCLK1}	Internal APB1 clock frequency	-	0	32	
f_{PCLK2}	Internal APB2 clock frequency	-	0	32	
V_{DD}	Standard operating voltage	BOR detector disabled	1.65	3.6	V
		BOR detector enabled, at power on	1.8	3.6	
		BOR detector disabled, after power on	1.65	3.6	
$V_{DDA}^{(1)}$	Analog operating voltage (ADC and DAC not used)	Must be the same voltage as $V_{DD}^{(2)}$	1.65	3.6	V
	Analog operating voltage (ADC or DAC used)		1.8	3.6	
V_{IN}	Input voltage on FT pins ⁽³⁾	$2.0\text{ V} \leq V_{DD} \leq 3.6\text{ V}$	-0.3	5.5	V
	Input voltage on BOOT0 pin	$1.65\text{ V} \leq V_{DD} \leq 2.0\text{ V}$	-0.3	5.25	
	Input voltage on any other pin		0	5.5	
			-0.3	$V_{DD}+0.3$	
P_D	Power dissipation at $T_A = 85\text{ °C}^{(4)}$	BGA100 package	-	339	mW
T_A	Temperature range	Maximum power dissipation	-40	85	°C
		Low power dissipation ⁽⁵⁾	-40	105	
T_J	Junction temperature range	$-40\text{ °C} \leq T_A \leq 105\text{ °C}$	-40	105	°C

- When the ADC is used, refer to [Table 54: ADC characteristics](#).
- It is recommended to power V_{DD} and V_{DDA} from the same source. A maximum difference of 300 mV between V_{DD} and V_{DDA} can be tolerated during power-up and operation.
- To sustain a voltage higher than $V_{DD}+0.3\text{ V}$, the internal pull-up/pull-down resistors must be disabled.
- If T_A is lower, higher P_D values are allowed as long as T_J does not exceed T_J max (see [Table 12: Thermal characteristics on page 53](#)).
- In low power dissipation state, T_A can be extended to this range as long as T_J does not exceed T_J max (see [Table 12: Thermal characteristics on page 53](#)).

Table 19. Current consumption in Sleep mode (continued)

Symbol	Parameter	Conditions		f _{HCLK}	Typ	Max ⁽¹⁾			Unit
						55 °C	85 °C	105 °C	
I _{DD} (Sleep)	Supply current in Sleep mode, code executed from Flash	MSI clock, 65 kHz	Range 3, V _{CORE} =1.2V VOS[1:0] = 11	65 kHz	40	70	70	80	μA
		MSI clock, 524 kHz		524 kHz	60	90	90	100	
		MSI clock, 4.2 MHz		4.2 MHz	210	250	250	260	

1. Guaranteed by characterization results, unless otherwise specified.
2. Oscillator bypassed (HSEBYP = 1 in RCC_CR register)
3. Tested in production

Table 22. Typical and maximum current consumptions in Stop mode

Symbol	Parameter	Conditions			Typ (1)	Max (1)(2)	Unit
I_{DD} (Stop with RTC)	Supply current in Stop mode with RTC enabled	RTC clocked by LSI, regulator in LP mode, HSI and HSE OFF (no independent watchdog)	LCD OFF	$T_A = -40^{\circ}\text{C}$ to 25°C $V_{DD} = 1.8\text{ V}$	1.2	2.75	μA
				$T_A = -40^{\circ}\text{C}$ to 25°C	1.4	4	
				$T_A = 55^{\circ}\text{C}$	2.6	6	
				$T_A = 85^{\circ}\text{C}$	4.8	10	
				$T_A = 105^{\circ}\text{C}$	10.2	23	
			LCD ON (static duty) ⁽³⁾	$T_A = -40^{\circ}\text{C}$ to 25°C	3.3	6	
				$T_A = 55^{\circ}\text{C}$	4.5	8	
				$T_A = 85^{\circ}\text{C}$	6.6	12	
				$T_A = 105^{\circ}\text{C}$	13.6	27	
			LCD ON (1/8 duty) ⁽⁴⁾	$T_A = -40^{\circ}\text{C}$ to 25°C	7.7	10	
				$T_A = 55^{\circ}\text{C}$	8.6	12	
				$T_A = 85^{\circ}\text{C}$	10.7	16	
				$T_A = 105^{\circ}\text{C}$	19.8	40	
		RTC clocked by LSE external clock (32.768 kHz), regulator in LP mode, HSI and HSE OFF (no independent watchdog)	LCD OFF	$T_A = -40^{\circ}\text{C}$ to 25°C	1.6	4	
				$T_A = 55^{\circ}\text{C}$	2.7	6	
				$T_A = 85^{\circ}\text{C}$	4.8	10	
				$T_A = 105^{\circ}\text{C}$	10.3	23	
			LCD ON (static duty) ⁽³⁾	$T_A = -40^{\circ}\text{C}$ to 25°C	3.6	6	
				$T_A = 55^{\circ}\text{C}$	4.6	8	
				$T_A = 85^{\circ}\text{C}$	6.7	12	
				$T_A = 105^{\circ}\text{C}$	10.9	23	
			LCD ON (1/8 duty) ⁽⁴⁾	$T_A = -40^{\circ}\text{C}$ to 25°C	7.6	10	
				$T_A = 55^{\circ}\text{C}$	8.6	12	
				$T_A = 85^{\circ}\text{C}$	10.7	16	
				$T_A = 105^{\circ}\text{C}$	19.8	40	
		RTC clocked by LSE (no independent watchdog) ⁽⁵⁾	LCD OFF	$T_A = -40^{\circ}\text{C}$ to 25°C $V_{DD} = 1.8\text{ V}$	1.45	-	
				$T_A = -40^{\circ}\text{C}$ to 25°C $V_{DD} = 3.0\text{ V}$	1.9	-	
				$T_A = -40^{\circ}\text{C}$ to 25°C $V_{DD} = 3.6\text{ V}$	2.2	-	

Table 24. Peripheral current consumption⁽¹⁾ (continued)

Peripheral		Typical consumption, V _{DD} = 3.0 V, T _A = 25 °C				Unit
		Range 1, V _{CORE} =1.8 V VOS[1:0] = 01	Range 2, V _{CORE} =1.5 V VOS[1:0] = 10	Range 3, V _{CORE} =1.2 V VOS[1:0] = 11	Low power sleep and run	
AHB	GPIOA	5	4.5	3.5	4	μA/MHz (f _{HCLK})
	GPIOB	5	4.5	3.5	4.5	
	GPIOC	5	4.5	3.5	4.5	
	GPIOD	5	4.5	3.5	4.5	
	GPIOE	5	4.5	3.5	4.5	
	GPIOH	4	4	3	3.5	
	CRC	1	0.5	0.5	0.5	
	FLASH	13	11.5	9	18.5	
	DMA1	12	10	8	10.5	
All enabled		166	138	106	130	
I _{DD} (RTC)		0.47				μA
I _{DD} (LCD)		3.1				
I _{DD} (ADC) ⁽³⁾		1450				
I _{DD} (DAC) ⁽⁴⁾		340				
I _{DD} (COMP1)		0.16				
I _{DD} (COMP2)	Slow mode	2				
	Fast mode	5				
I _{DD} (PVD / BOR) ⁽⁵⁾		2.6				
I _{DD} (IWDG)		0.25				

1. Data based on differential I_{DD} measurement between all peripherals OFF and one peripheral with clock enabled, in the following conditions: f_{HCLK} = 32 MHz (Range 1), f_{HCLK} = 16 MHz (Range 2), f_{HCLK} = 4 MHz (Range 3), f_{HCLK} = 64kHz (Low power run/sleep), f_{APB1} = f_{HCLK}, f_{APB2} = f_{HCLK}, default prescaler value for each peripheral. The CPU is in Sleep mode in both cases. No I/O pins toggling.
2. HSI oscillator is OFF for this measure.
3. Data based on a differential I_{DD} measurement between ADC in reset configuration and continuous ADC conversion (HSI consumption not included).
4. Data based on a differential I_{DD} measurement between DAC in reset configuration and continuous DAC conversion of V_{DD}/2. DAC is in buffered mode, output is left floating.
5. Including supply current of internal reference voltage.

6.3.6 External clock source characteristics

High-speed external user clock generated from an external source

In bypass mode the HSE oscillator is switched off and the input pin is a standard GPIO. The external clock signal has to respect the I/O characteristics in [Section 6.3.13](#). However, the recommended clock input waveform is shown in [Figure 15: High-speed external clock source AC timing diagram](#).

Table 26. High-speed external user clock characteristics⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{HSE_ext}	User external clock source frequency	CSS is on or PLL is used	1	8	32	MHz
		CSS is off, PLL not used	0			
V_{HSEH}	OSC_IN input pin high level voltage	-	$0.7V_{DD}$	-	V_{DD}	V
V_{HSEL}	OSC_IN input pin low level voltage		V_{SS}	-	$0.3V_{DD}$	
$t_{w(HSEH)}$ $t_{w(HSEL)}$	OSC_IN high or low time		12	-	-	ns
$t_{r(HSE)}$ $t_{f(HSE)}$	OSC_IN rise or fall time		-	-	20	
$C_{in(HSE)}$	OSC_IN input capacitance	-	-	2.6	-	pF
$DuCy_{(HSE)}$	Duty cycle	-	45	-	55	%
I_L	OSC_IN Input leakage current	$V_{SS} \leq V_{IN} \leq V_{DD}$	-	-	± 1	μA

1. Guaranteed by design.

Figure 15. High-speed external clock source AC timing diagram

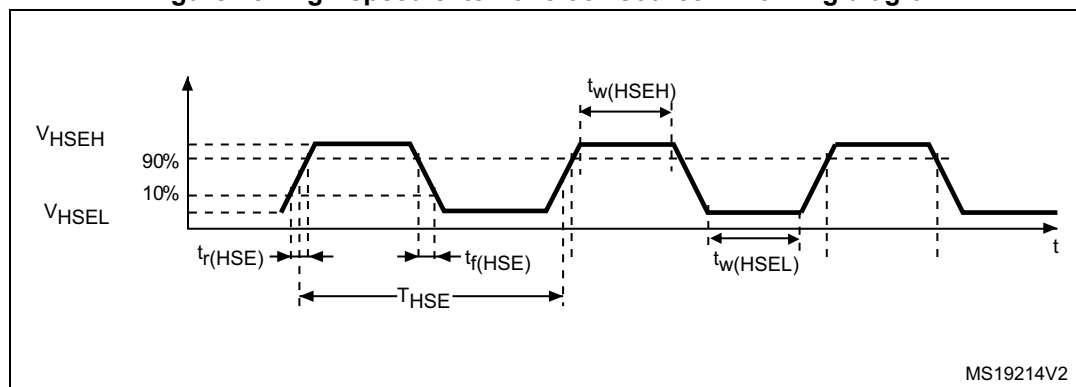


Table 51. USB DC electrical characteristics

Symbol	Parameter	Conditions	Min. ⁽¹⁾	Max. ⁽¹⁾	Unit
Input levels					
V _{DD}	USB operating voltage ⁽²⁾	-	3.0	3.6	V
V _{DI} ⁽³⁾	Differential input sensitivity	I(USB_DP, USB_DM)	0.2	-	V
V _{CM} ⁽³⁾	Differential common mode range	Includes V _{DI} range	0.8	2.5	
V _{SE} ⁽³⁾	Single ended receiver threshold	-	1.3	2.0	
Output levels					
V _{OL} ⁽⁴⁾	Static output level low	R _L of 1.5 kΩ to 3.6 V ⁽⁵⁾	-	0.3	V
V _{OH} ⁽⁴⁾	Static output level high	R _L of 15 kΩ to V _{SS} ⁽⁵⁾	2.8	3.6	

1. All the voltages are measured from the local ground potential.
2. To be compliant with the USB 2.0 full speed electrical specification, the USB_DP (D+) pin should be pulled up with a 1.5 k Ω resistor to a 3.0-to-3.6 V voltage range.
3. Guaranteed by characterization results.
4. Tested in production.
5. R_L is the load connected on the USB drivers.

Figure 25. USB timings: definition of data signal rise and fall time

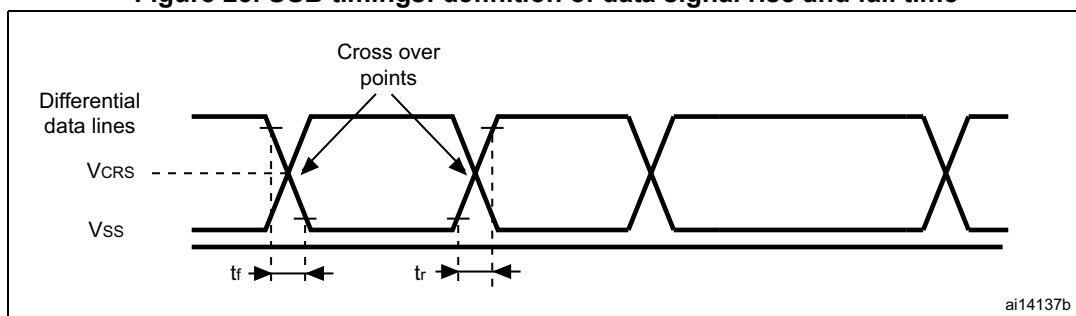


Table 52. USB: full speed electrical characteristics

Driver characteristics ⁽¹⁾					
Symbol	Parameter	Conditions	Min	Max	Unit
t_r	Rise time ⁽²⁾	$C_L = 50$ pF	4	20	ns
t_f	Fall Time ⁽²⁾	$C_L = 50$ pF	4	20	ns
t_{rfm}	Rise/ fall time matching	t_r/t_f	90	110	%
V_{CRS}	Output signal crossover voltage		1.3	2.0	V

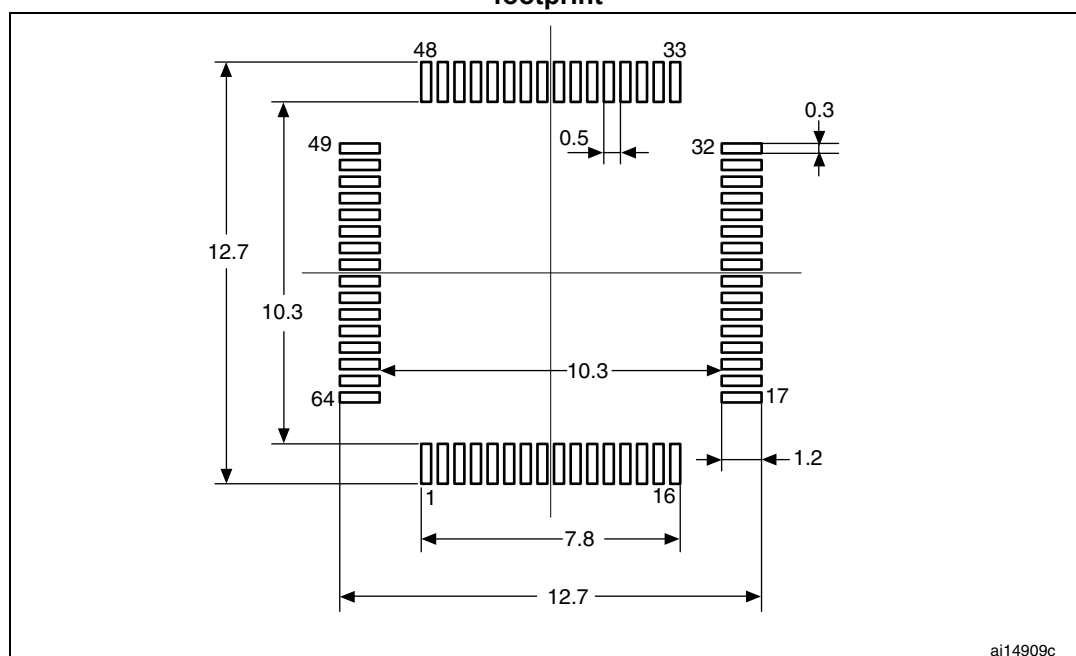
1. Guaranteed by design.
2. Measured from 10% to 90% of the data signal. For more detailed informations, please refer to USB Specification - Chapter 7 (version 2.0).

Table 64. LQFP64 10 x 10 mm, 64-pin low-profile quad flat package mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Typ	Min	Max
E3	-	7.500	-	-	0.2953	-
e	-	0.500	-	-	0.0197	-
K	0°	3.5°	7°	0°	3.5°	7°
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

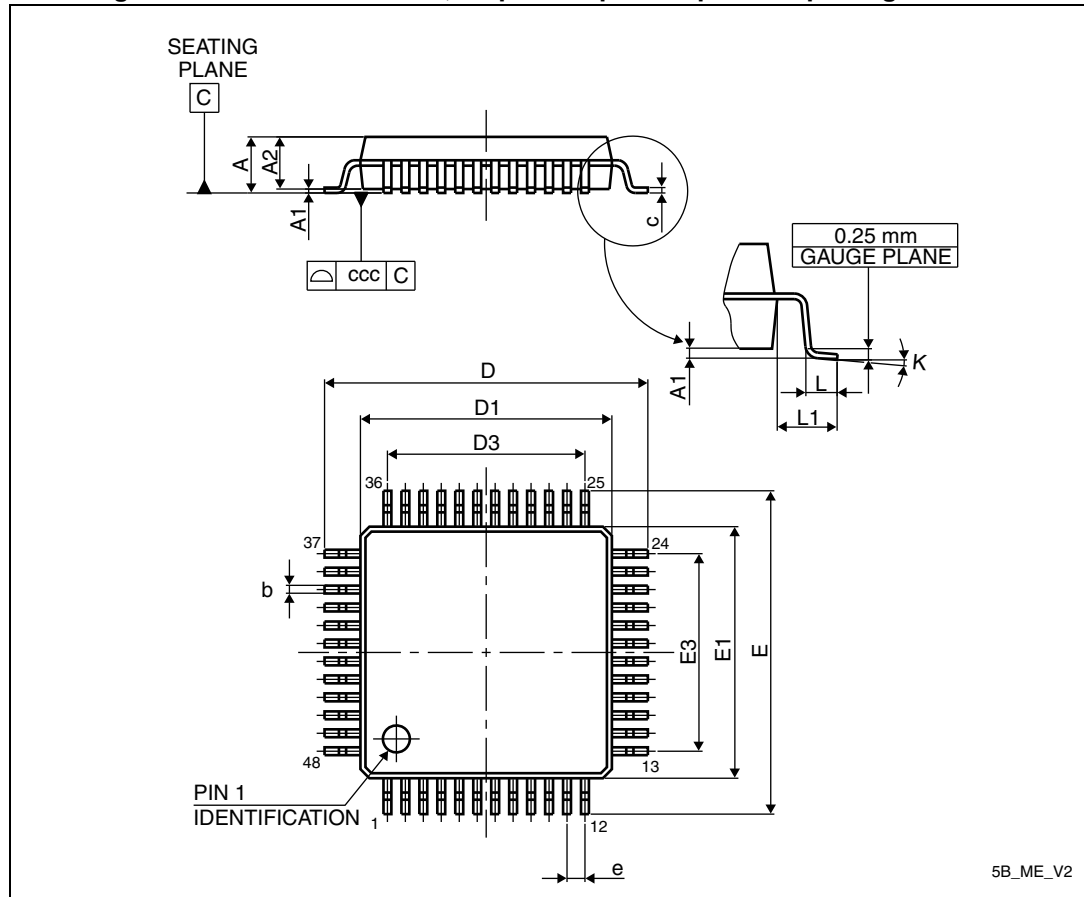
Figure 36. LQFP64 10 x 10 mm, 64-pin low-profile quad flat package recommended footprint



1. Dimensions are in millimeters.

7.3 LQFP48 7 x 7 mm, 48-pin low-profile quad flat package information

Figure 38. LQFP48 7 x 7 mm, 48-pin low-profile quad flat package outline

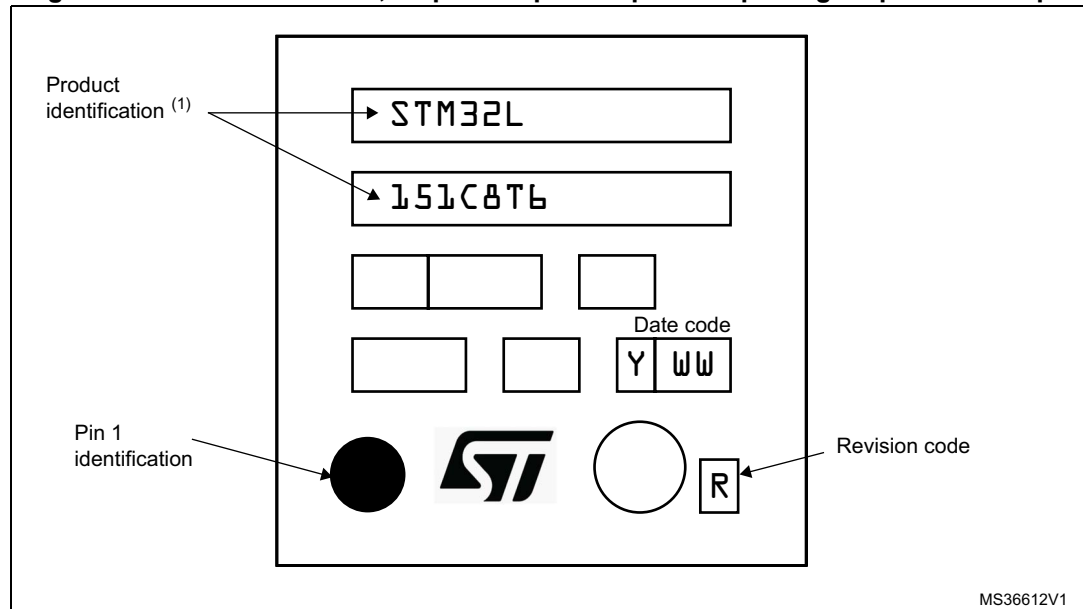


1. Drawing is not to scale.

LQFP48 device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

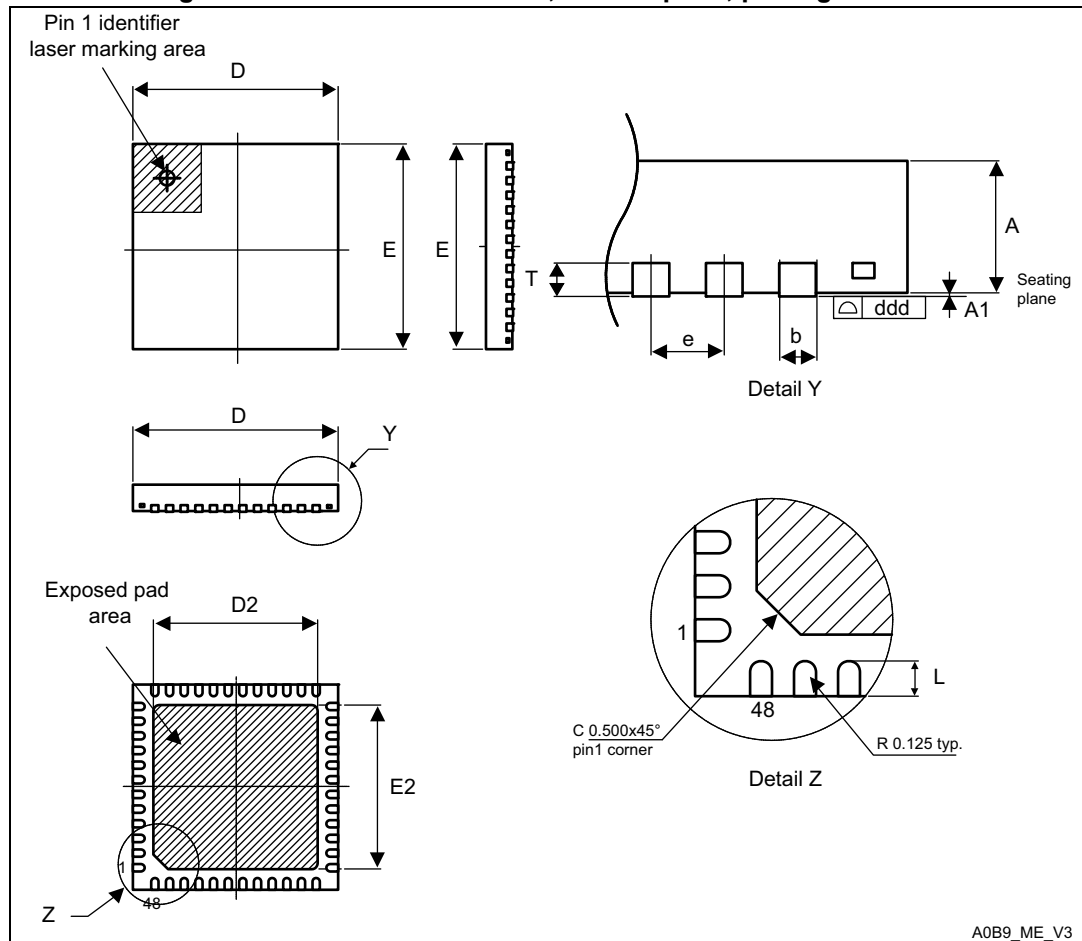
Figure 40. LQFP48 7 x 7 mm, 48-pin low-profile quad flat package top view example



1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

7.4 UFQFPN48 7 x 7 mm, 0.5 mm pitch, package information

Figure 41. UFQFPN48 7 x 7 mm, 0.5 mm pitch, package outline



1. Drawing is not to scale.
2. All leads/pads should also be soldered to the PCB to improve the lead/pad solder joint life.
3. There is an exposed die pad on the underside of the UFQFPN package. It is recommended to connect and solder this back-side pad to PCB ground.

8 Ordering information

Table 72. Ordering information scheme

Example:	STM32	L	151	C	8	T	6	T	TR
Device family									
STM32 = ARM-based 32-bit microcontroller									
Product type									
L = Low power									
Device subfamily									
151: Devices without LCD									
152: Devices with LCD									
Pin count									
C = 48 pins									
R = 64 pins									
V = 100 pins									
Flash memory size									
6 = 32 Kbytes of Flash memory									
8 = 64 Kbytes of Flash memory									
B = 128 Kbytes of Flash memory									
Package									
H = BGA									
T = LQFP									
U = UFQFPN									
Temperature range									
6 = Industrial temperature range, -40 to 85 °C									
Options									
No character = V _{DD} range: 1.8 to 3.6 V and BOR enabled									
T = V _{DD} range: 1.65 to 3.6 V and BOR disabled									
Packing									
TR = tape and reel									
No character = tray or tube									

For a list of available options (speed, package, etc.) or for further information on any aspect of this device, please contact your nearest ST sales office.